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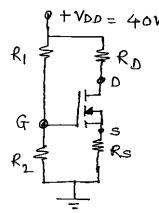
[5352]-532

S.E. (E & TC/Electronics) (I Semester) EXAMINATION, 2018 ELECTRONIC DEVICES AND CIRCUITS (2015 PATTERN)

Time : Two Hours Maximum Marks: 50

(i) Answer Q. 1 or 2, 3 or 4, 5 or 6, 7 or 8.

- (ii) Neat diagram must be drawn wherever necessary.
- Use of logarithm tables, slide rule, Mollier charts, electronic pocket calculator and steam table is allowed.
- Assume suitable data, if necessary. (iv)
- 1. Explain the following terms with respect to JFET: (a) [6]
 - Pinch off voltage (Vp) (i)
 - Cut-off voltage $(V_{GS}(off))$ (ii)
 - Forward transconductor (g_m) .
 - For the circuit shown in figure 1. Calculate I_{DQ} , V_{DSQ} (*b*) V_D. [6]



Assume:

$$R_1 = 22 M\Omega, R_D = 3 k\Omega$$

$$R_2$$
 = 18 M Ω , V_{TN} = 3 V, R_S = 0.82 k Ω

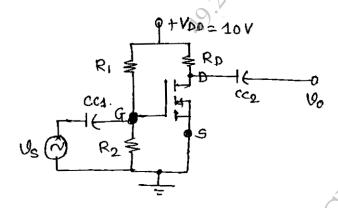
$$R_2 = 18 \text{ M}\Omega, V_{TN}$$
 $K_n = 0.12 \text{ mA/V}^2$
 $V_{GS} = 10.48 \text{ V}$
(Figure 1)

$$V_{CS} = 10.48 \text{ V}$$

- 2. (a) Draw and explain the small signal mode of the JFET. [6]
 - (b) Explain the following non-ideal voltage current characteristics of EMOSFET:
 - (i) Finite output resistance
 - (ii) Body effect
 - (iii) Subthreshold conduction.
- 3. (a) Draw the common source E-MOSFET amplifier and explain its modes of operation in detail. [7]
 - (b) Draw and explain the working of MOSFET as current sink and source. [6]

Or

4. (a) For the circuit diagram shown in figure 2, calculate Av, Ri and Ro.



(Figure 2)

Assume:

$$R_1 = 10 M\Omega$$

[6]

$$R_2 = 3.6 M\Omega$$

$$K_n = 0.5 \text{ mA/V}^2$$

$$\lambda = 0.01 \text{ V}^{-1}$$

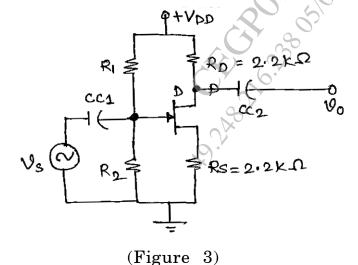
$$V_{TN} = 1.5 \text{ V}$$

(b) Write a short note on "MOSFET as Active resistor." [6] [5352]-532

- **5.** (a) What is the effect of negative feedback on the following parameters: [8]
 - (1) Gain stability
 - (2) Bandwidth
 - (3) Input impedance
 - (4) Out impedance.
 - (b) Draw and explain the Hartley oscillator. Give equation for frequency of oscillation. [5]

Or

6. (a) For the circuit diagram shown in figures, calculate the β, Rif,Rof and Gmf. [8]



Assume:

$$R_1 = 10 M\Omega$$

$$R_2 = 1 M\Omega$$

$$R_D = 2.2 k\Omega$$

$$R_S = 2.2 k\Omega$$

$$Y_{OS} = 20 \mu s$$

$$g_{\rm m} = 2.4 \, \text{MA/V}$$

(b) State Barkhausen criteria and draw RC phase shift oscillator.

[5]

7. (a) Draw and explain the internal block diagram of negative three terminal adjustable Voltage regulators. [8]

(*b*) Write a short note on Boost SMPS. [4]

- Draw the detailed block diagram of SMPS and explain its 8. (a) operation. [8]
 - Design and adjustable voltage regulator using LM 317 for output (*b*) voltage from 10 to 20 V and draw the typical connection diagram. -00 μA.
 -00 μA.
 -00 μΑ.
 -00 μΑ.
 -00 μΑ.

Assume : $R_1 = 240 \Omega$ and Iadj. 100 μ A. [4]

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